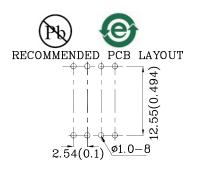


Part Number: XEUY29DX

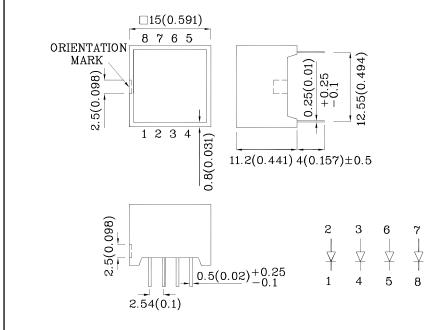
 $15 \mathrm{mmx} 15 \mathrm{mm} \ \mathrm{LIGHT} \ \mathrm{BAR}$

Features

- Robust package
- ullet Uniform light disbursement
- \bullet Ideal for backlighting logos or icons
- Excellent for flush mounting
- ullet RoHS compliant



Package Schematics



Notes

1. All dimensions are in millimeters (inches), Tolerance is $\pm 0.25 (0.01")$ unless otherwise noted.

2. Specifications are subject to change without notice.

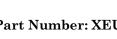
	UY (GaAsP/GaP)	Unit		
Reverse Voltage	$V_{\rm R}$	5	V	
Forward Current	I_{F}	30	mA	
Forward Current (Peak) 1/10 Duty Cycle 0.1ms Pulse Width	ifs	140	mA	
Power Dissipation	P_{D}	75	mW	
Operating Temperature	T _A -40 ~ +85		°C	
Storage Temperature	Tstg	-40 ~ +85	-0	
Lead Solder Temperature [2mm Below Package Base]	260°C For 3-5 Seconds			

Operating Characteristics (T _A =25°C)	UY (GaAsP/GaP)	Unit	
Forward Voltage (Typ.) (I _F =10mA)	V_{F}	1.95	V
Forward Voltage (Max.) (I _F =10mA)	V_{F}	2.5	V
Reverse Current (Max.) $(V_R=5V)$	I_R	10	uA
Wavelength of Peak Emission CIE127-2007* (Typ.) (I _F =10mA)	λΡ	590*	nm
Wavelength of Dominant Emission CIE127-2007* (Typ.) $(I_F=10\text{mA})$	λD	588*	nm
Spectral Line Full Width At Half-Maximum (Typ.) (I _F =10mA)	$\triangle \lambda$	35	nm
Capacitance (Typ.) (V _F =0V, f=1MHz)	С	20	pF

 Part Number	Emitting Color	Emitting Material	Luminous Intensity CIE127-2007* (I _F =10mA) mcd		Wavelength CIE127-2007* nm λP	Lens-color
			min.	typ.		
XEUY29DX	Yellow	GaAsP/GaP	21 5.6*	34 11*	590*	Yellow Diffused

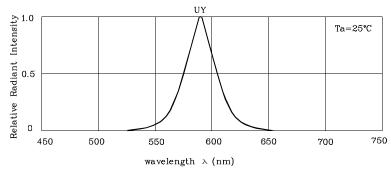
^{*}Luminous intensity value and wavelength are in accordance with CIE127-2007 Mar 05.2014

XDSA1966 V6-X Layout: Maggie L.



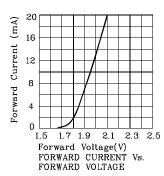


15mmx15mm LIGHT BAR

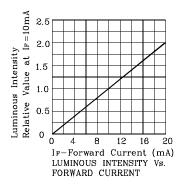


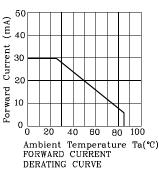
RELATIVE INTENSITY Vs. CIE WAVELENGTH

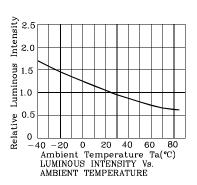
\$ UY



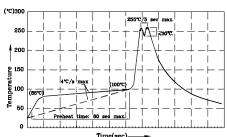
www.SunLEDusa.com







Wave Soldering Profile for Thru-Hole Products (Pb-Free Components)



- 1. Recommend pre-heat temperature of 105°C or less (as measured with a thermocouple attached to the LED pins) prior to immersion in the solder wave with a maximum solder bath temperature of 260°C
 2. Peak wave soldering temperature between 245°C ~ 255°C for 3 sec (5 sec
- 2.Peak wave soldering temperature between 245U ~ 25U CM S SEC U max).
 3.Do not apply stress to the epoxy resin while the temperature is above 4.Fixtures should not incur stress on the component when mounting and during soldering process.
 5.SAC 305 solder alloy is recommended.
 6.No more than one wave soldering pass.

Remarks:

If special sorting is required (e.g. binning based on forward voltage, luminous intensity / luminous flux, or wavelength),

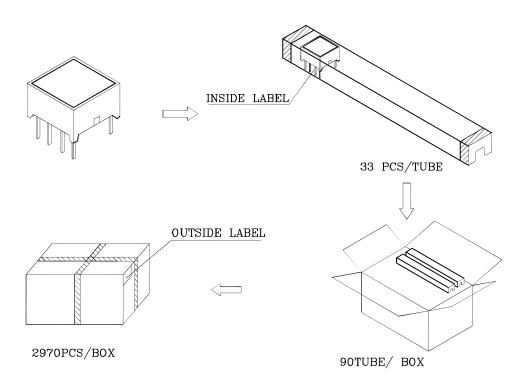
the typical accuracy of the sorting process is as follows:

- 1. Wavelength: +/-1nm
- 2. Luminous Intensity / Luminous Flux: +/-15%
- 3. Forward Voltage: +/-0.1V

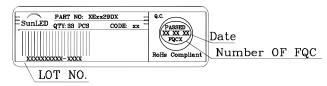
Note: Accuracy may depend on the sorting parameters.



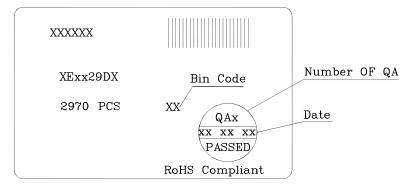
PACKING & LABEL SPECIFICATIONS



Inside Label On IC-tube



Outside Label On Box



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- 2. Contents within this document are subject to improvement and enhancement changes without notice.
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Mar 05,2014